

August 2008

QEC112, QEC113 Plastic Infrared Light Emitting Diode

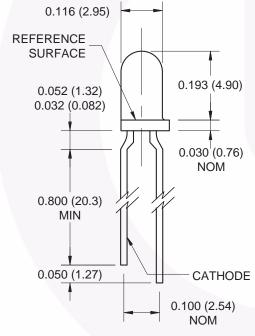
Features

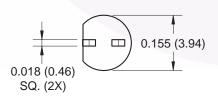
- $\lambda = 940$ nm
- Chip material = GaAs
- Package type: T-1 (3 mm)
- Can be used with QSCXXX Photosensor
- Narrow Emission Angle, 8° at 80% intensity
- High Output Power
- Package material and color: Clear, peach tinted plastic

Description

The QEC11X is an 940nm GaAs LED encapsulated in a clear peach tinted, plastic T-1 package.

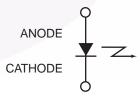
Package Dimensions







Schematic



Notes:

- 1. Dimensions of all drawings are in inches (mm).
- 2. Tolerance is ±0.010 (.25) on all non-nominal dimensions unless otherwise specified.

Absolute Maximum Ratings (T_A = 25°C unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating	Units
T _{OPR}	Operating Temperature	-40 to +100	°C
T _{STG}	Storage Temperature	-40 to +100	°C
T _{SOL-I}	Soldering Temperature (Iron) ^(2,3,4)	240 for 5 sec	°C
T _{SOL-F}	Soldering Temperature (Flow) ^(2,3)	260 for 10 sec	°C
I _F	Continuous Forward Current	50	mA
V _R	Reverse Voltage	5	V
P _D	Power Dissipation ⁽¹⁾	100	mW

Notes:

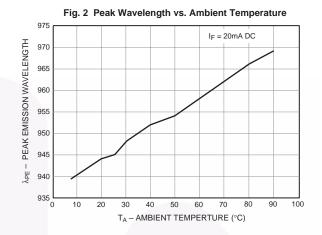
- 1. Derate power dissipation linearly 1.33mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6mm) minimum from housing.

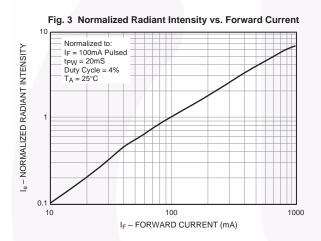
Electrical / Optical Characteristics (T_A = 25°C)

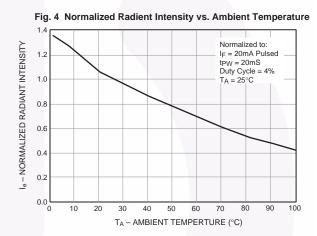
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
λ _{PE}	Peak Emission Wavelength	I _F = 100mA		940		nm
TC_λ	Temperature Coefficient			0.3		nm/°C
2⊖ ¹ /2	Emission Angle	I _F = 100mA		18		0
V _F	Forward Voltage	$I_F = 100 \text{mA}, \text{ tp} = 20 \text{ms}$			1.5	V
TC _{VF}	Temperature Coefficient			-2		mV/°C
I _R	Reverse Current	V _R = 5V			10	μΑ
IE	Radiant Intensity QEC112	$I_F = 100 \text{mA}, \text{ tp} = 20 \text{ms}$	6		30	mW/sr
IE	Radiant Intensity QEC113	$I_F = 100 \text{mA}, \text{ tp} = 20 \text{ms}$	14	40		mW/sr
TC _{IE}	Temperature Coefficient			-0.7		%/°C
t _r	Rise Time	I _F = 100mA		800		ns
t _f	Fall Time			800		ns
C _j	Junction Capacitance	V _R = 0V		14		pF

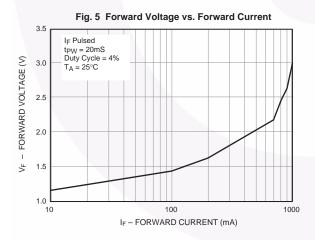
Typical Performance Curves

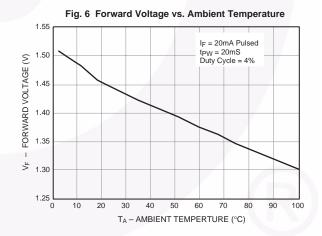
Fig. 1 Normalized Intensity vs. Wavelength 1.0 0.9 0.8 NORMALIZED INTENSITY 0.7 0.6 0.5 0.4 0.3 0.2 0.1 750 800 850 900 950 1,000 1,050 λ (nm)





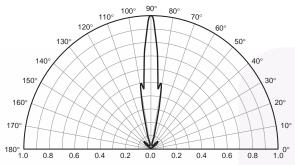


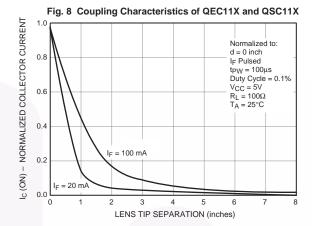




Typical Performance Curves (Continued)

Fig. 7 Radiation Diagram









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